onsemi

Bipolar Transistor

(-)50 V, (-)5 A, Low V_{CE}(sat), Complementary Dual CPH5

CPH5520

Features

- Composite Type with a PNP Transistor and an NPN Transistor Contained in One Package, Facilitating High–Density Mounting
- Ultrasmall Package Facilitate Miniaturization in End Products. (0.9 mm Mounting Height)
- This is a Pb–Free Device

Applications

• Relay Drivers, Lamp Drivers, Motor Drivers, Gate Drivers

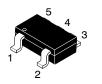
Specifications

(): PNP

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Falametei	Symbol	Conditions	пашуз	Onit
Collector-to-Base Voltage	V _{CBO}		(–50)80	V
Collector-to-Emitter Voltage	V _{CEO}		(–50)50	V
Emitter-to-Base Voltage	V _{EBO}		(–)6	V
Collector Current	۱ _C		(–)2	А
Collector Current (Pulse)	I _{CP}		(–)5	A
Base Current	Ι _Β		(–)400	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600 mm ² \times 0.8 mm) 1 unit	0.9	W
Total Power Dissipation	PT	Mounted on a ceramic board (600 mm ² \times 0.8 mm)	1.2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		–55 to +150	°C

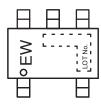
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



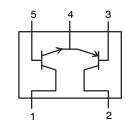
1: Collector (NPN TR) 2: Collector (PNP TR) 3: Base (PNP TR) 4: Emitter Common 5: Base (NPN TR)

CPH5 CASE 318BC

MARKING DIAGRAM



ELECTRICAL CONNECTION



ORDERING INFORMATION

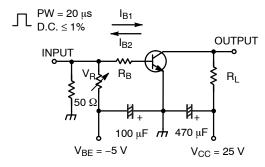
Device	Package	Shipping [†]
CPH5520-TL-E	CPH5 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

ELECTRICAL CHARACTERISTICS (Ta = 25° C)

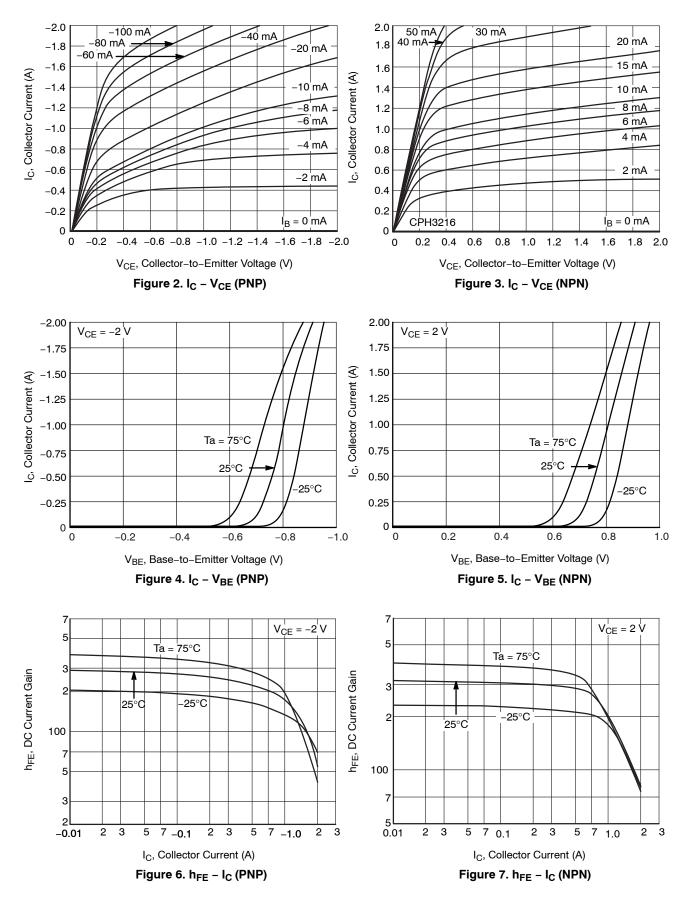
			Ratings			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)40 V, I _E = 0 A	-	-	(–)1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4 V, I _C = 0 A	-	-	(–)1	μΑ
DC Current Gain	h _{FE}	V _{CE} = (-)2 V, I _C = (-)100 mA	200	-	560	
Gain-Bandwidth Product	f _T	V _{CE} = (–)10 V, I _C = (–)300 mA	-	420	-	MHz
Output Capacitance	Cob	V _{CB} = (–)10 V, f = 1 MHz	-	(16)8	-	pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = (–)1 A, I _B = (–)50 mA	-	(-165)130	(-330)260	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = (-)1 A, I _B = (-)50 mA		(–)0.9	(–)1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = (–)10 μA, I _E = 0 A	(-50)80	_	-	V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	$I_{C} = (-)1 \text{ mA}, R_{BE} = \infty$	(-50)50	-	-	V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = (–)10 μA, I _C = 0 A	(–)6	_	-	V
Turn-On Time	t _{on}	See specified Test Circuit	-	(35)35	-	ns
Storage Time	t _{stg}	1	-	(200)330	-	ns
Fall Time	t _f	1	-	(24)40	_	ns

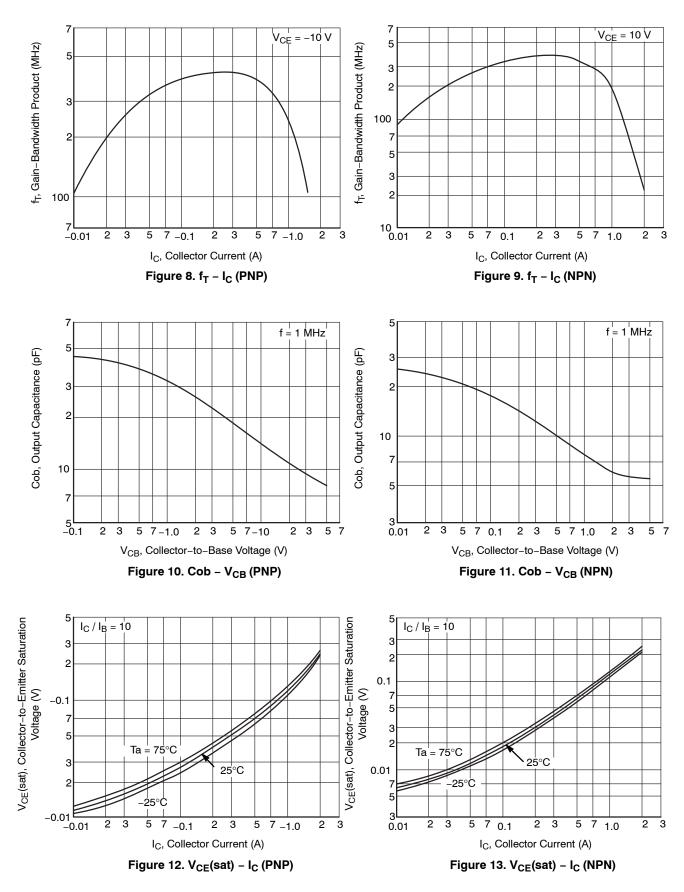
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

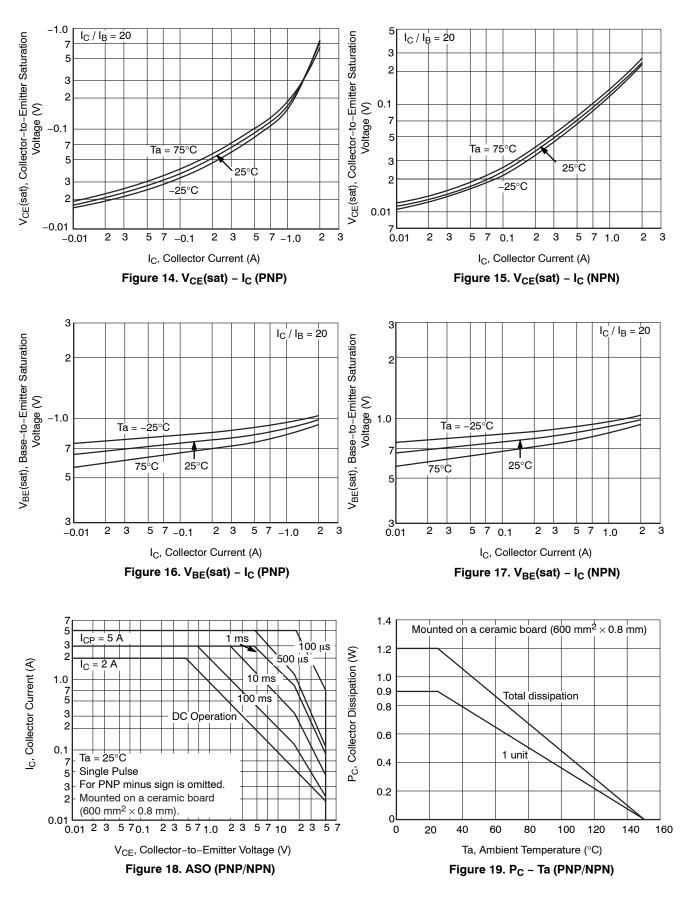


$$\begin{split} I_C &= 10I_{B1} = -10I_{B2} = 0.7 \ A \\ For \ PNP, \ the \ polarity \ is \ reversed. \end{split}$$

Figure 1. Switching Time Test Circuit



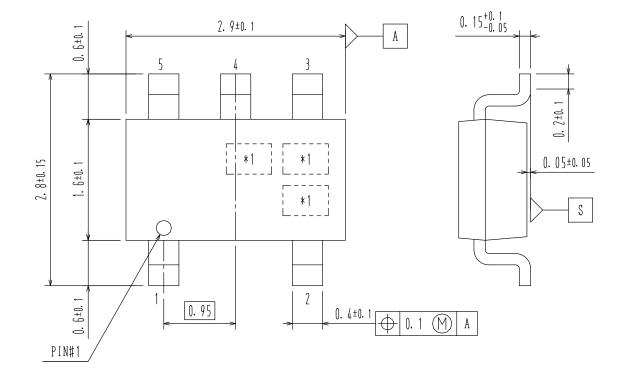


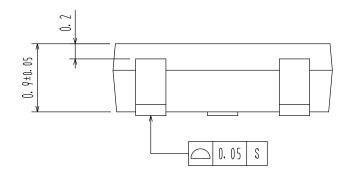




CPH5 CASE 318BC ISSUE O

DATE 30 NOV 2011





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